

Vishay Siliconix

Low Power, High Voltage SPST Analog Switches

DESCRIPTION

The DG447, DG448 are dual supply single-pole/single-throw (SPST) switches. On resistance is 25 W maximum and flatness is 2.2 W max over the specified analog signal range. These analog switches were designed to provide high speed, low error switching of precision analog signals. The primary application areas are in the routing and switching in telecommunications and test equipment. Combining low power, low leakages, low on-resistance and small physical size, the DG477, DG448 are also ideally suited for portable and battery powered industrial and military equipment.

The DG477 has one normally closed switch, while the DG448 switch is normally open. They operate either from a single + 7 V to 36 V supply or from dual \pm 4.5 V to \pm 20 V supplies. They are offered in the very popular, small TSOP6 package.

FEATURES

- ± 15 V analog signal range
- On-resistance $R_{DS(on)}$: 25 Ω max.
- Fast switching action t_{ON}: 100 ns
- V_L logic supply not required
- TTL CMOS input compatible
- Rail to rail signal handling
- Dual or single supply operation
- Compliant to RoHS Directive 2002/95/EC

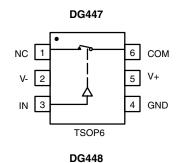
BENEFITS

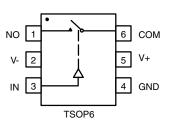
- Wide dynamic range
- · Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing
- Reduced board space
- Improved reliability

APPLICATIONS

- Precision test equipment
- Precision instrumentation
- Communications systems
- PBX, PABX systems
- Audio equipment
- · Redundant systems
- PC multimedia boards
- Hard disc drives

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





TRUTH TABLE							
Logic DG447 DG448							
0	ON	OFF					
1	OFF	ON					

 $\begin{array}{l} \text{Logic "0"} \leq 0.8 \ \text{V} \\ \text{Logic "1"} \geq 2.4 \ \text{V} \end{array}$

Device Marking: DG447DV = G5xxx DG448DV = G6xxx

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DG447, DG448

Vishay Siliconix



ORDERING INFORMATION							
Temp. Range Package Part Number							
DG447, DG448							
- 40 °C to 85 °C	6-pin TSOP	DG447DV-T1-E3					
- 40 C 10 85 C	6-pill 130F	DG448DV-T1-E3					

ABSOLUTE MAXIMUM RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)						
Parameter Referenced to V-	Limit	Unit				
V+	44					
GND		25	V			
Digital Inputs ^a , V _{no/nc} , V _{COM}	(V-) - 2 V to (V+) + 2 V or 30 mA, whichever occurs first	•				
Current, (Any Terminal) Continuous	30	mA				
Current (NO or NC or COM) Pulsed at 1 ms, 10 % Duty Cycl	100					
Storage Temperature		- 65 to 150	°C			
Power Dissipation (Package) ^b 6-pin TSOP ^c		570				

Notes: a. Signals on NO, NC, COM, or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC board. c. Derate 7 mW/°C above 70 °C.

SPECIFICATIONS ^a							
		Test Conditions Unless Otherwise Specified		D Suffix - 40 °C to 85 °C			
		V+ = 15 V, V- = - 15 V				-	-
Parameter	Symbol	V _{IN} = 2.4 V, 0.8 V ^f	Temp. ^b	Min. ^d	Typ. ^c	Max. ^d	Uni
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	- 15		15	V
Drain-Source On-Resistance	R _{ON}	I _{no/nc} = 10 mA, V _{COM} = 10 V V+ = 13.5 V, V- = - 13.5 V	Room Full		17	25 30	Ω
On-Resistance Flatness	R _{ON} Flatness	I _{no/nc} = 10 mA, V _{COM} = ± 5 V, 0 V V+ = 13.5 V, V- = - 13.5 V	Room Full		0.8	2.2 3	52
Switch Off Leakage Current	I _{no/nc(off)}	V+ = 16.5, V- = - 16.5 V V _{COM} = ± 15.5 V	Room Full	- 1 - 10	- 0.1	1 10	
Switch On Leakage Current	I _{COM(off)}	$V_{no/nc} = -/+ 15.5 V$	Room Full	- 1 - 10	- 0.1	1 10	nA
Channel On Leakage Current	I _{COM(on)}	$V + = 16.5 V, V - = -16.5 V_{COM} = V_{no/nc} = \pm 15.5 V$	Room Full	- 1 - 10	- 0.1	1 10	
Digital Control							
Input, High Voltage	I _{INH}		Full	2.4			
Input, Low Voltage	I _{INL}		Full			0.8	V
Input Capacitance ^e	C _{IN}		Room		5		pF
Input Current	I _{IN}	$V_{IN} = 0 \text{ or } 5 \text{ V}$		- 1		1	μA
Dynamic Characteristics							
Turn-On Time	t _{ON}		Room Full		100	130 140	ns
Turn-Off Time	tOFF	$R_L = 300 \ \Omega, C_L = 35 \ pF$ $V_{no/nc} = \pm 10 \ V$	Room Full		50	95 110	115
Charge Injection ^e	Q	$C_L = 10 \text{ nF}, V_{gen} = 0 \text{ V}, R_{gen} = 0 \Omega$	Room		10		pC
Off-Isolation ^e	OIRR	C_L = 5 pF, R_L = 50 Ω, f = 1 MHz	Room		- 72		dB
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room		19		
Drain Off Capacitance ^e	C _{D(off)}		Room		8		pF
Channel On Capacitance ^e	C _{D(on)}	f = 1 MHz	Room		30		
Power Supplies							
Positive Supply Current	l+	V+ = 16.5 V, V- = - 16.5 V	Room Full		16	30 50	μA
Negative Supply Current	l-	V _{IN} = 0 or 5 V	Room Full	- 1 - 10	- 0.02		μΑ

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		Test Conditions Unless Otherwise Specified		D Suffix - 40 °C to 85 °C			
Parameter	Symbol	V+ = 12 V, V- = 0 V V _{IN} = 2.4 V, 0.8 V ^f	Temp. ^b	Min. ^d	Typ. ^c	Max. ^d	Unit
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	0		12	V
Drain-Source On-Resistance	R _{ON}	I _{no/nc} = - 10 mA, V _{COM} = 8 V V+ = 10.8 V	Room Full		32	45 60	Ω
On-Resistance Flatness	R _{ON} Flatness	$I_{no/nc} = 10 \text{ mA}, V_{COM} = 2, 6, 8 \text{ V}$ V+ = 10.8 V	Room Full		2	6 8	Ω
Dynamic Characteristics	•	•					
Turn-On Time	t _{ON}	V _{NO. NC} = ± 10 V, R _L = 300 Ω, C _L = 35 pF	Room Full		140	175 225	nS
Turn-Off Time	t _{OFF}	NO, NC - 1 10 V, NL - 500 SZ, OL - 55 PI	Room Full		50	120 150	113
Charge Injection ^e	Q	C_{L} = 10 nF, V_{gen} = 0 V, R_{gen} = 0 Ω	Room		12		рС
Power Supplies		·					
Positive Supply Current	I+	V+ = 13.2 V, V _{IN} = 0 V, 5 V	Room Full		22	50 75	μA

Notes:

a. Refer to PROCESS OPTION FLOWCHART.

b. Room = 25 °C, full = as determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

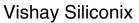
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

e. Guaranteed by design, not subject to production test.

f. V_{IN} = input voltage to perform proper function.

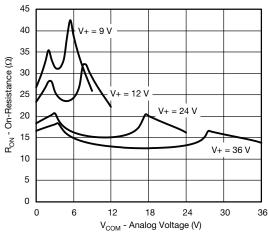
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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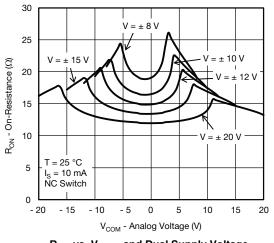




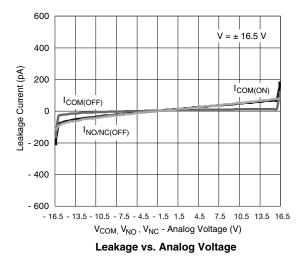
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

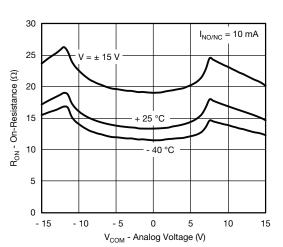


 $\rm R_{ON}$ vs. $\rm V_{COM}$ and Single Supply Voltage

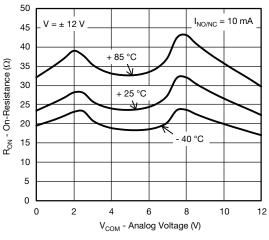


 $\rm R_{ON}$ vs. $\rm V_{COM}\,$ and Dual Supply Voltage

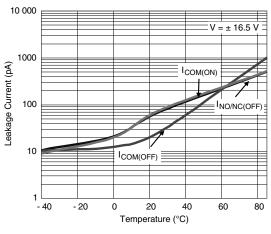




R_{ON} vs. Analog Voltage and Temperature



R_{ON} vs. Analog Voltage and Temperature

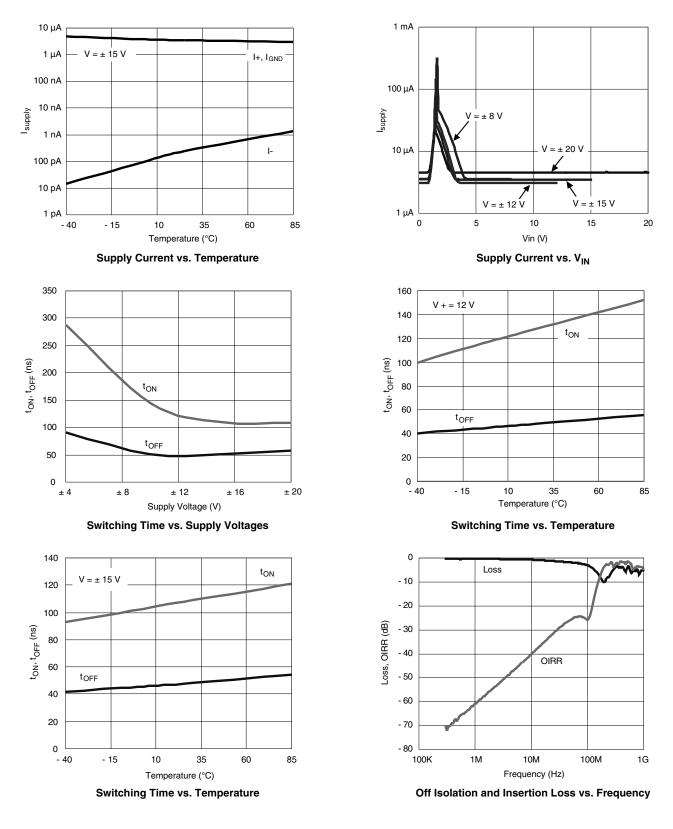


Leakage Current vs. Temperature

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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



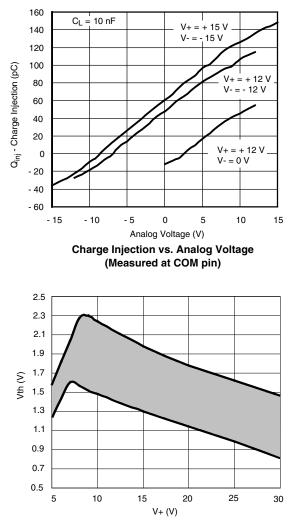
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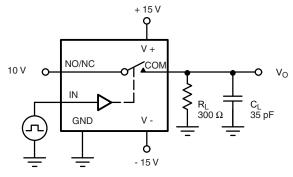
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Input Switching Threshold vs. Supply Voltage

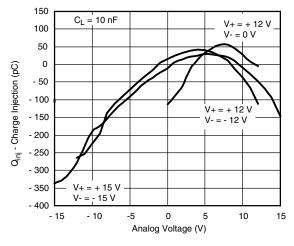
TEST CIRCUITS

 $V_{\mbox{O}}$ is the steady state output with the switch on.



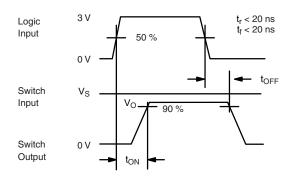
C_L (includes fixture and stray capacitance)

$$V_0 = V_S$$
 $\frac{R_L}{R_I + r_{ON}}$



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Charge Injection vs. Analog Voltage (Measured at NC or NO pin)



Note: Logic input waveform is inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

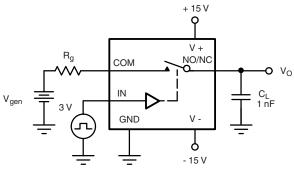
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TEST CIRCUITS

V_O is the steady state output with the switch on.



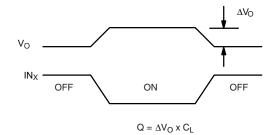
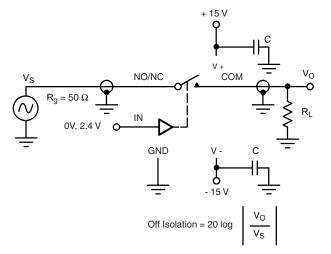


Figure 2. Charge Injection



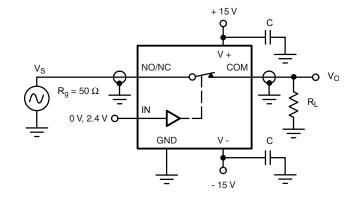


Figure 3. Off Isolation

Figure 4. Insertion Loss

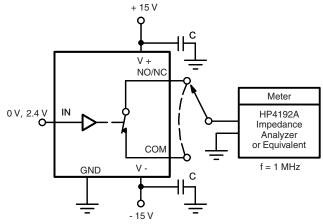
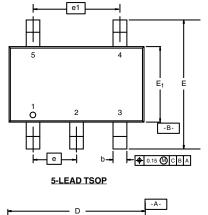


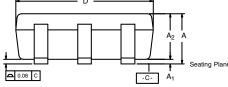
Figure 5. Source/Drain Capacitances

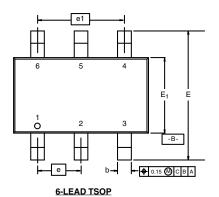
Vishay General Semiconductor

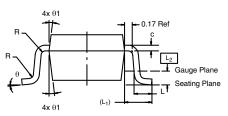


TSOP: 5/6-LEAD JEDEC Part Number: MO-193C









DIM.		MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
А	0.91	-	1.10	0.036	-	0.043		
A ₁	0.01	-	0.10	0.0004	-	0.004		
A ₂	0.90	-	1.00	0.035	0.038	0.039		
b	0.30	0.32	0.45	0.012	0.013	0.018		
С	0.10	0.15	0.20	0.004	0.006	0.008		
D	2.95	3.05	3.10	0.116	0.120	0.122		
E	2.70	2.85	2.98	0.106	0.112	0.117		
E ₁	1.55	1.65	1.70	0.061	0.065	0.067		
е	0.95 BSC			0.0374 BSC				
e ₁	1.80	1.90	2.00	0.071	0.075	0.079		
L	0.32	-	0.50	0.012	-	0.020		
L ₁		0.60 Ref.		0.024 Ref.				
L ₂	0.25 BSC				0.010 BSC			
R	0.10	-	-	0.004	-	-		
θ	0°	4°	8°	0°	4°	8°		
θ_1	7° Nom.				7° Nom.			

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?73854.

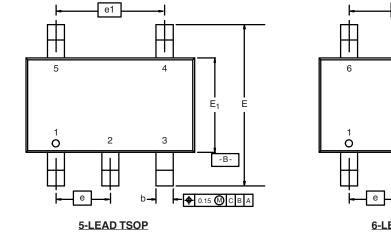
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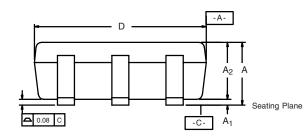


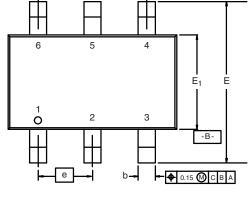
Package Information

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TSOP: 5/6-LEAD JEDEC Part Number: MO-193C



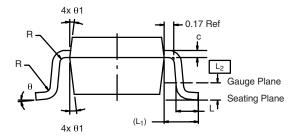




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6-LEAD TSOP

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	MIL	LIMETER	RS	INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
Е	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е		0.95 BSC		0.0374 BSC			
e ₁	1.80	1.90	2.00	0.071	0.075	0.079	
L	0.32	-	0.50	0.012	-	0.020	
L ₁		0.60 Ref		0.024 Ref			
L ₂		0.25 BSC		0.010 BSC			
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ_1	7° Nom 7° Nom						
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

Application Note 826

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RECOMMENDED MINIMUM PADS FOR TSOP-6



Recommended Minimum Pads Dimensions in Inches/(mm)

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